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1Gbit (128Mx8bit / 64Mx16bit) NAND Flash 1. SUMMARY DESCRIPTION The Hynix HY27UF(08/16)1G2A series is a 128Mx8bit with spare 4Mx8 bit capacity. The device is offered in 3.3V Vcc Power Supply. Its NAND cell provides the most cost-effective solution for the solid state mass storage market. The memory is divided

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#### **1 Gb NAND Flash H27U1G8F2B - Natisbad.org**

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#### **SK Hynix Introduces Industry's Highest 72-Layer 3D NAND Flash**

SK Hynix calls its technology 4D NAND because it uses a combination of 3D Charge Trap Flash technology (CTF) as well as Periphery Under Cell (PUC). According to the vendor, using 96-layers can achieve 49% improved bit density over the company's previous 72-layer 3D NAND products.

#### **SK Hynix Shipping 96-Layer QLC 4D NAND Flash to SSD ...**

The NAND in the Gold S31 SSDs is SK Hynix's fourth generation 3D NAND, a 72-layer design that is competing against the 64L and to some extent 92/96L generations from other manufacturers.

#### **The SK Hynix Gold S31 SATA SSD Review: Hynix 3D NAND ...**

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NAND Flash MT29F. NAND Flash - Mass Storage. Micron Technology Inc. Micron's discrete NAND Flash memory is available in a wide range of densities, voltages, and configurations so it's easy to design in to any storage application—from storage cards to mobile internet devices (MIDs) to enterprise servers.

#### **NAND Flash MT29F - Micron Technology Inc. - FLASH | Online ...**

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flash memory cells) along with a separate flash memory controller chip. The NAND type is found primarily in memory cards, USB flash drives, solid-state drives (those produced in 2009 or later), and similar products, for general storage and transfer of data.

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Both are PCI-Express 3.0 x4, NVMe 1.3 drives, built entirely with in-house hardware, i.e., the controller, DRAM cache, and of course the 128-layer 4D NAND flash are all made by SK Hynix. The Platinum P31 comes in just 2 TB capacity with 1,500 TBW endurance; while the Gold P31 comes in 500 GB and 1 TB capacities, with 375 TBW and 750 TBW, respectively.

#### **A Walk Through SK Hynix at CES 2020: 4D NAND SSDs and DDR5 ...**

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#### **8Gb NAND FLASH - OLPC**

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